# NSN 5962-01-234-1359

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## **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.4 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Om-51a/fr **Features Provided:** Hermetically sealed and burn in and programmable and w/active pull-up and w/enable **Inclosure Material:** Ceramic Inclosure Configuration: Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input

#### **Case Outline Source And Designator:**

D-3 mil-m-38510

#### **Terminal Surface Treatment:**

Gold or solder

#### **Voltage Rating And Type Per Characteristic:**

-0.5 volts power source and 7.0 volts power source

#### **Time Rating Per Chacteristic:**

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level

output

#### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

#### **Precious Material And Location:**

Terminal surface option gold

#### **Precious Material:**

Gold

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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## AeroBase Group

### Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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